

(C-014-D) DC-DC LLC Full-Bridge Converter (Discrete)

Simulation Parameters (Dialog)

Name	Content	unit	Default Value	Variable Range
Transformer	Np: Primary-turns	turns	18	1 ~ 1000
	Ns: Secondary-turns	turns	1	1 ~ 1000
	Lm: Magnetizing Inductance	H	60u	1n~1
Rp	Transformer Resistance	Ω	5m	1m ~ 1
Rs	Transformer Resistance	Ω	1m	1m ~ 1
Lr	Resonant Inductance	H	12u	1n ~ 1
Cr	Resonant Capacitance	F	100n	1n ~ 1
Cout	Output Capacitance	F	4.7m	1n ~ 1
	Initial Voltage	V	50	0 ~ 80
ESR	ESR of Cout	Ω	15m	1m ~ 1
Primary	Thcap_Primary	Thermal Capacitance	J/K	0.1 ~ 100
	Rth_Primary	Thermal Resistance	K/W	0.1 ~ 100
	TGND_Primary	Ambient Temperature	°C	-40 ~ 175
Secondary	Thcap_Secondary	Thermal Capacitance	J/K	0.1 ~ 100
	Rth_Secondary	Thermal Resistance	K/W	0.1 ~ 100
	TGND_Secondary	Ambient Temperature	°C	-40 ~ 175

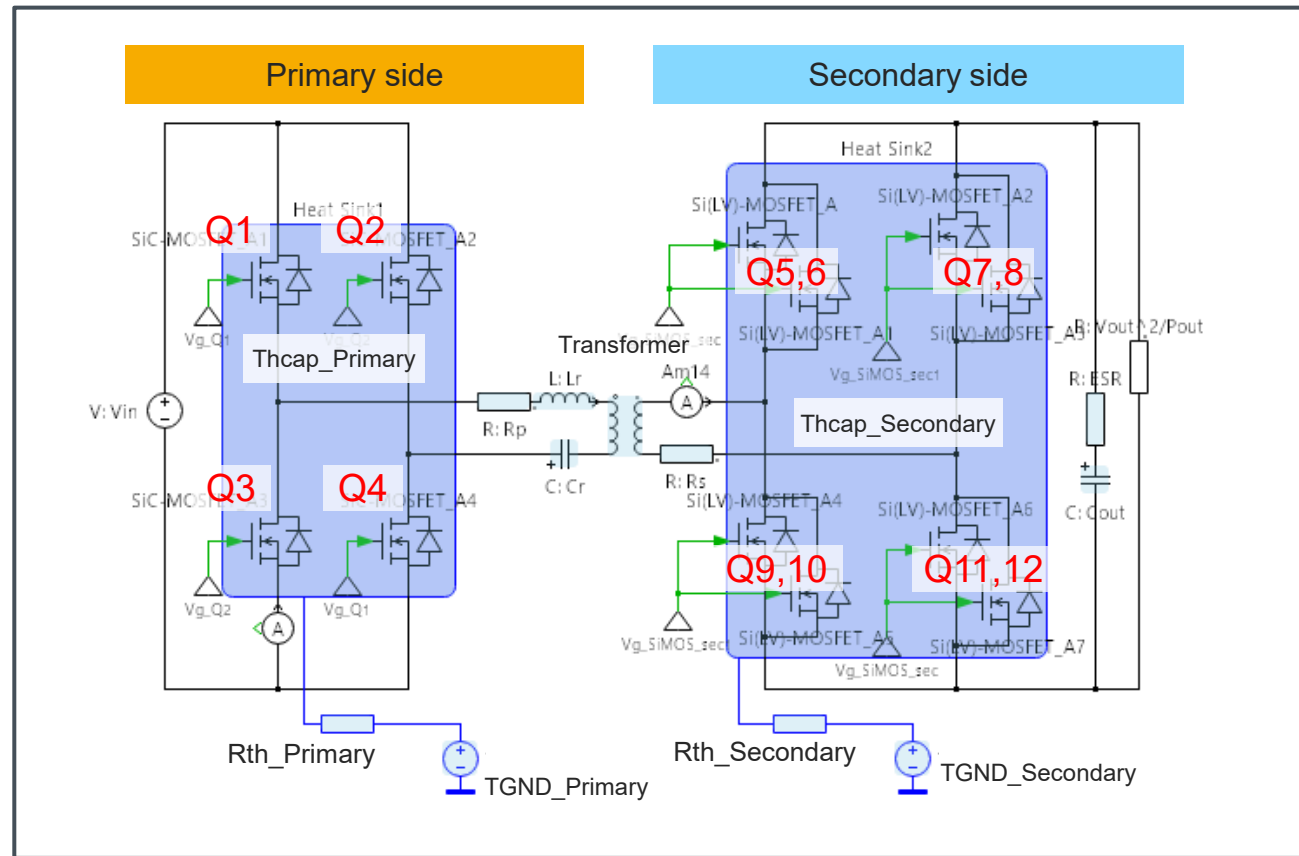
Simulation Parameters (Table)

Name	Content	unit	Default Value	Variable Range	
Test_time	Test time in simulation	s	0.2	10u ~ 0.5	
Vin_dc	Input Voltage	V	800	400 ~ 1,200	
Vout_dc	Output Voltage	V	50	1 ~ 1200	
Pout	Output Power	W	10k	100~30k	
fs_ref	Target Carrier Frequency	Hz	100k	10k~500k	
Primary	Rg_on 1*	Gate Resistance (Source)	Ω	4.7	0.1 ~ 100
	Rg_off 1*	Gate Resistance (Sink)	Ω	2.0	0.1 ~ 100
	DT1	Dead Time	s	100n	0 ~ 1m
Secondary	Rg_on 2*	Gate Resistance (Source)	Ω	10	0.1 ~ 100
	Rg_off 2*	Gate Resistance (Sink)	Ω	10	0.1 ~ 100
	DT2	Dead Time	s	100n	0 ~ 1m
T_init**	Initial Junction Temp.	°C	25	-40 ~ 175	

*Common for all MOSFETs in the same side.

**Common for all devices

Simulation Circuit



Default Devices

Name	Device Type	Part No.	Specification
Q1~4	SiC MOSFET	SCT4018KR	1200V/ 81A/ 18mΩ/ TO-247-4L
Q5~12	Si MOSFET	RS7N200BH	80V/ 200A/ 1.7mΩ/ DFN5060-8S

Schematic window

- Dialog parameters setting
- Results display

The screenshot displays the PLECS simulation environment. On the left, a schematic diagram of a power converter is shown with various components like MOSFETs, diodes, and capacitors. Below the schematic is a table of power loss components.

Component	Value
MOSFET_primary	101.09 [W]
MOSFET_secondary	9915.13 [W]
Diode	97.79 [W]
Capacitor	14.19 [W]
Inductor	14.29 [W]
Transformer	29.60 [W]
Conduction Loss	6.33 [W]
Switching Loss	5.76 [W]
Total Loss	49.14 [W]

On the right, a series of waveforms are displayed, including input voltage, MOSFET gate and drain voltages, and junction temperatures. The bottom section shows a table for device parameters and simulation controls.

Parameter	Value
[Primary] SIC-MOSFET	SCT4836KR (1200V/36mQ/TO-247-4L)
[Secondary] Low-Voltage MOSFET	RS7N200GH (80V/1.7mQ/DFN560-8S)

Simulation Control: Start, Steady-state, Hold Results. Simulation Completed.

Waveforms

Device selection

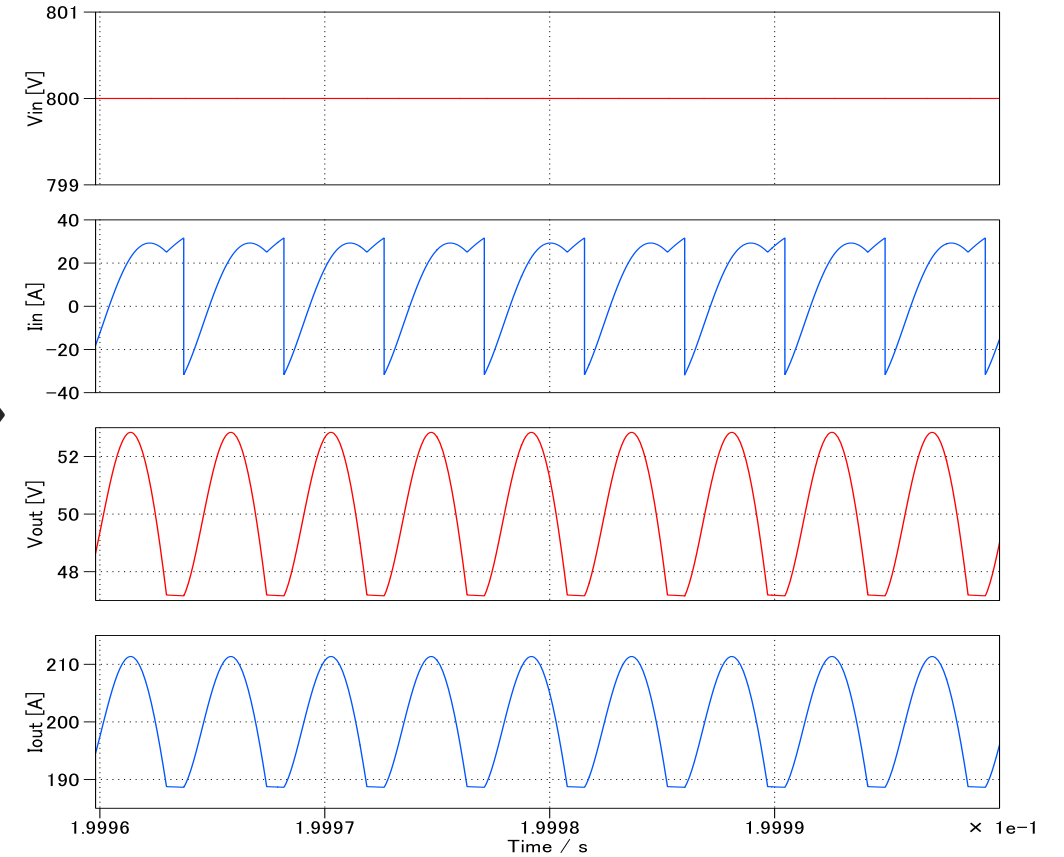
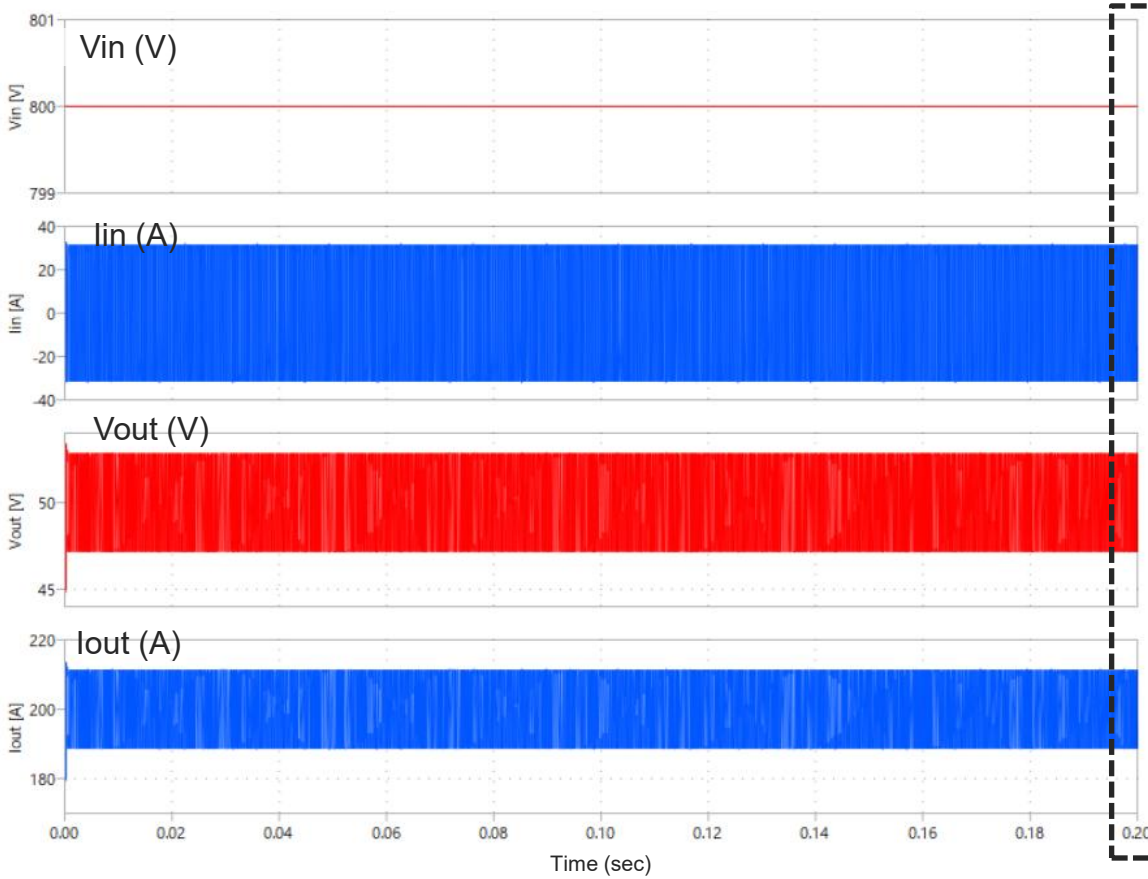
Table parameters setting

Simulation control

Trace selection

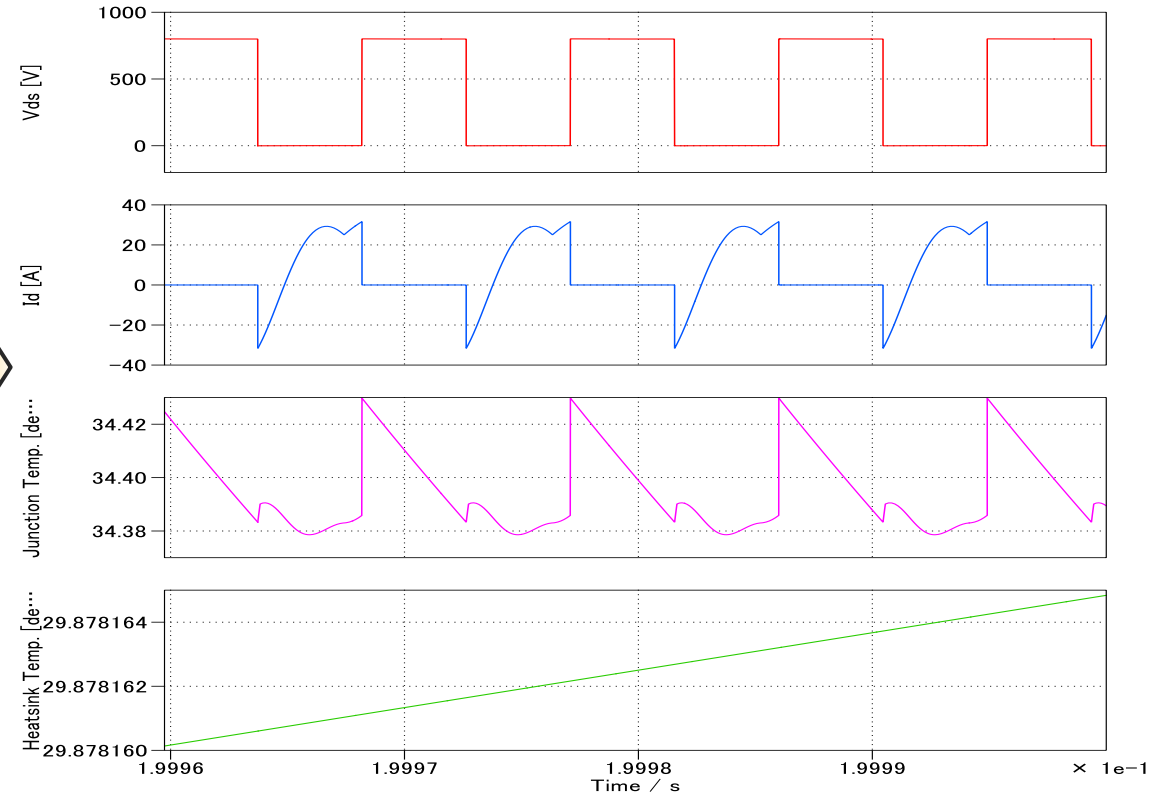
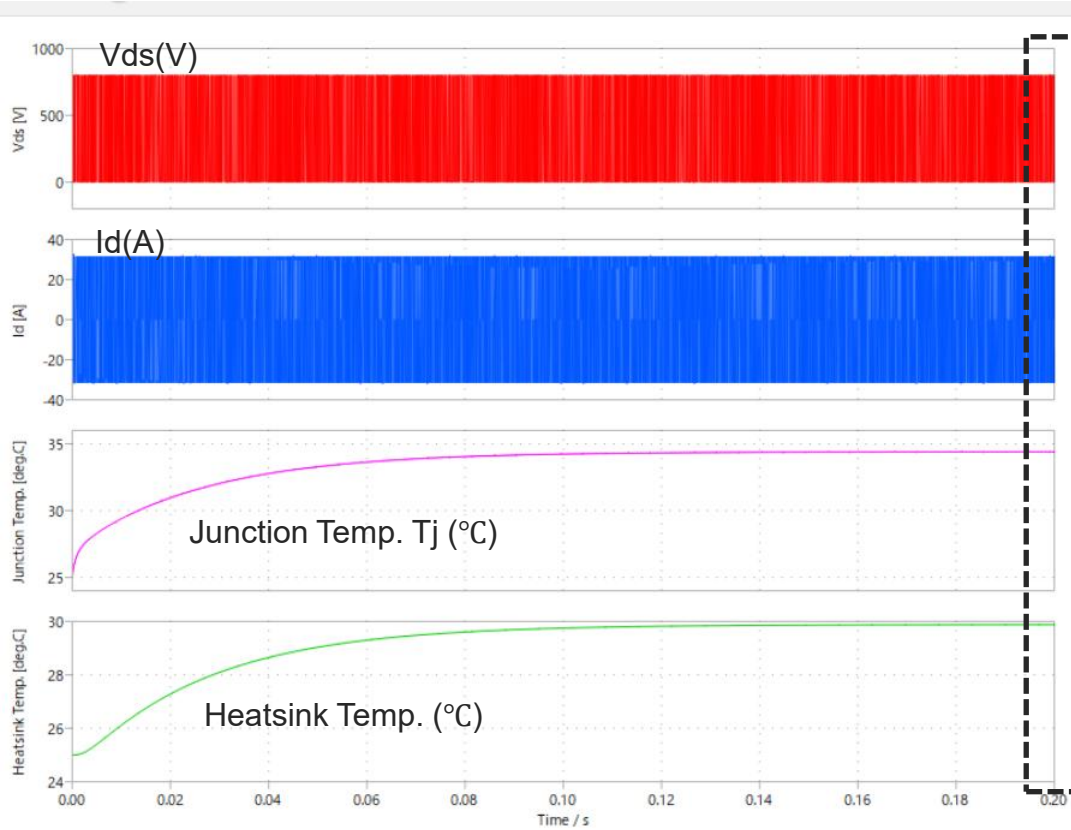
Simulation Results 1

Input and Output



Contents	Results
Input Power : Pin	10.140 (kW)
Output Power: Pout	9.915 (kW)
Efficiency: η	97.79 (%)

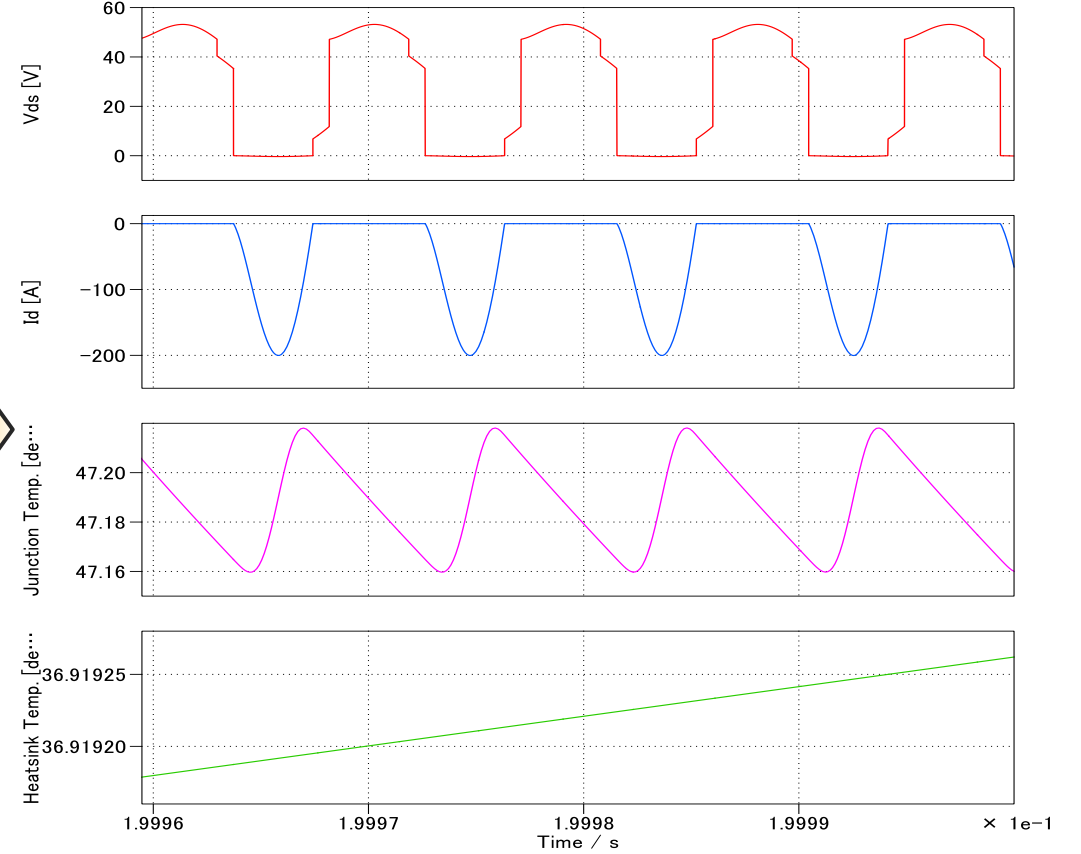
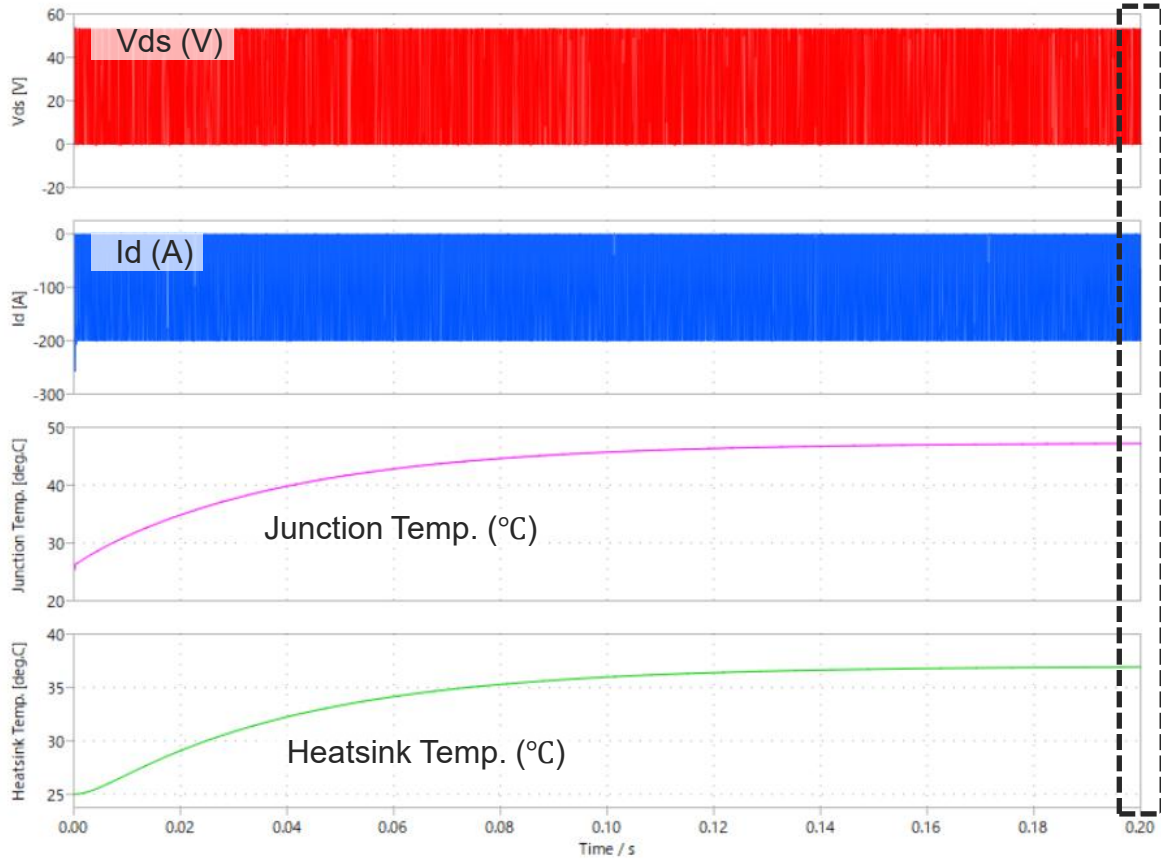
Primary side



Contents	Results
Conduction Loss: Pcond (primary)	6.33 (W/device)
Switching Loss: Psw (primary)	5.78 (W/device)
Junction Temp.: Tj (primary)	34.39 (°C)
Heatsink Temp.: T_hs (primary)	29.88 (°C)
Total Loss: Ptot (primary)	48.44 (W)

Simulation Results 3

Secondary side

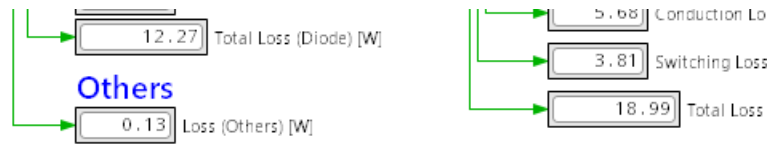


Contents	Results
Conduction Loss: Pcond (secondary)	14.70 (W/device)
Junction Temp. : Tj (secondary)	47.19 (°C)
Heatsink Temp.: T_hs (secondary)	36.92 (°C)
Total Loss: Ptot (secondary)	117.64 (W)

How to change the devices

The figure of "(A-011-D) DC-AC Totem-Pole PFC Diode Rectification (Discrete)" is used as an example in this page.

Device Selection



Device Selection

Parameter	Value
Part No. (SiC-MOSFET)	SCT4065DR (750V/65mΩ/TO-220...
Part No. (SiC-Schottky Barrier Diode)	SCS320AG (650V/20A/TO-220...



Loss breakdown diagram showing:
Total Loss (Diode) [W]: 12.27
Loss (Others) [W]: 0.13

Device Selection

Parameter	Value
Part No. (SiC-MOSFET)	SCT4065DR (750V/65mΩ/TO-220...
Part No. (SiC-Schottky Barrier Diode)	SCS320AG (650V/20A/TO-220...

- [SCT4036DWA \(750V/36mΩ/TO-263-7LA\)](#)
- [SCT4045DWA \(750V/45mΩ/TO-263-7LA\)](#)
- [SCT4065DWA \(750V/65mΩ/TO-263-7LA\)](#)
- [SCT4013DLL \(750V/13mΩ/TOLL\)](#)**
- [SCT4026DLL \(750V/26mΩ/TOLL\)](#)
- [SCT4036DLL \(750V/36mΩ/TOLL\)](#)
- [SCT4045DLL \(750V/45mΩ/TOLL\)](#)

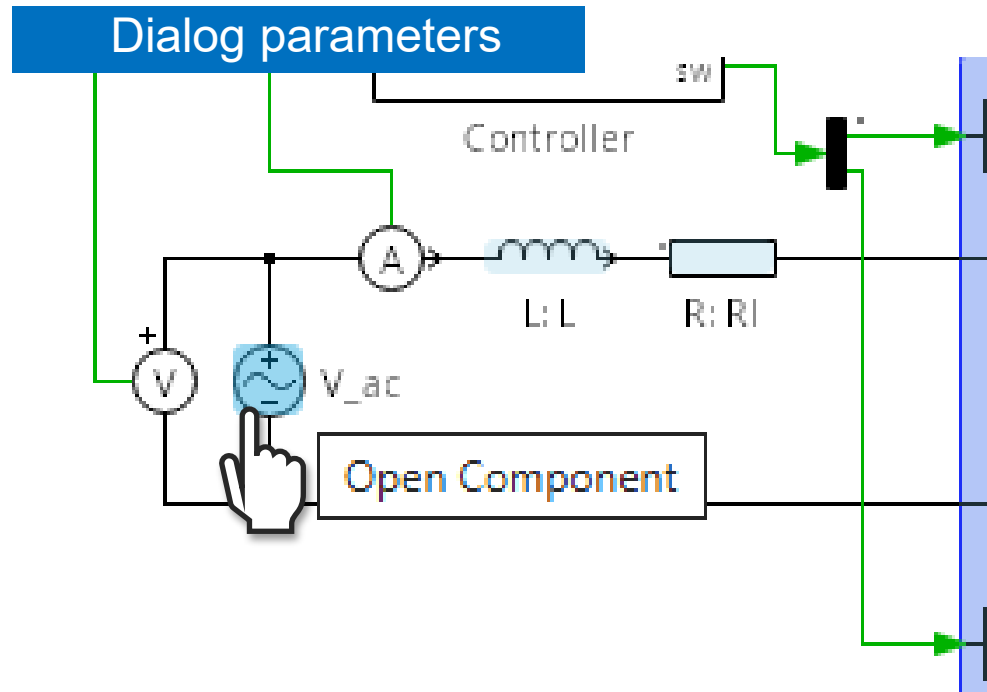
Over your mouse cursor to the device name that you want to change and click the left button of the mouse.

Available device lists are appeared like the above, and you can select a favorite device from these.

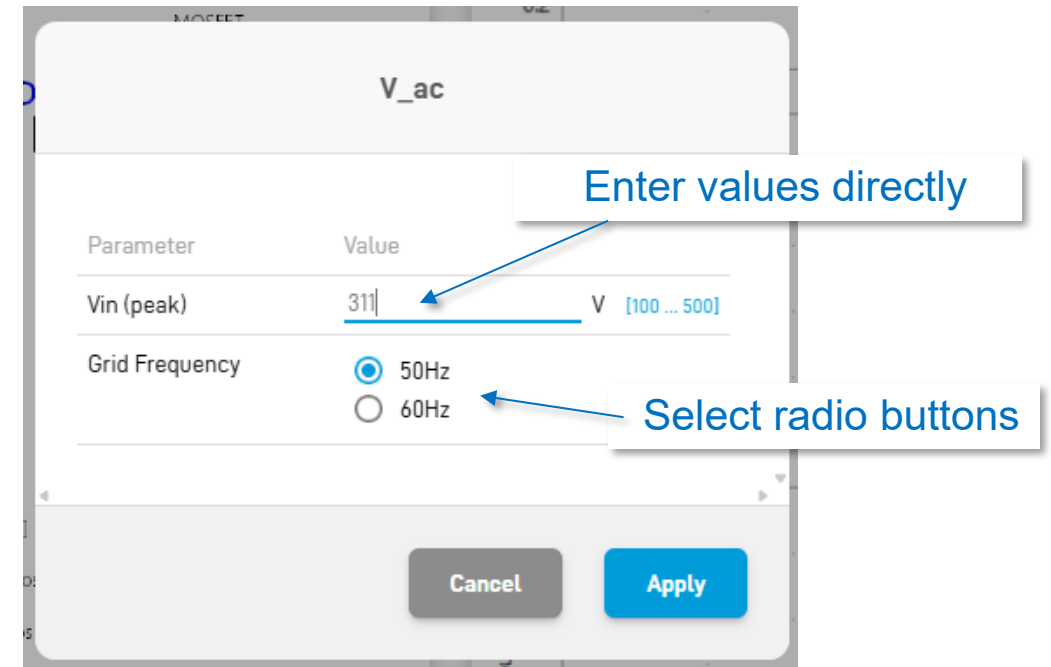
How to change Dialog parameters

The figure of "(A-011-D) DC-AC Totem-Pole PFC Diode Rectification (Discrete)" is used as an example in this page.

- Symbols whose parameters can be changed are colored light-blue in the circuit diagram.
- Over your mouse cursor to the symbol that you want to change the parameter and the symbol color is turned to blue (e.g. "V_ac" symbol in the below).
- Click the mouse's left button.



- A new window like the below is opened.
- You can change the parameters by entering the value directly* or selecting radio buttons.
- Push "Apply" button after changing all parameters.



*Note: Parameters can be entered directly are limited by Min. and Max. values to avoid unexpected system errors.
(e.g. "Vin(peak)" is limited between 100 and 500V in the above.)

How to change Table parameters

The figure of "(A-011-D) DC-AC Totem-Pole PFC Diode Rectification (Discrete)" is used as an example in this page.

ROHM PLECS Simulator
Circuit Information



2026 March
68UG117E Rev.001

Table parameters

General Conditions

Parameter	Value
Test_time	1 sec
Switching Frequency	60000 Hz

Device Conditions

General Conditions

Parameter	Value
Test_time	1 sec
Switching Frequency	<u>20000</u> Hz [10000 ... 100000]

Device Conditions

Choose the parameter that you want change on the parameter tables (e.g. "60kHz" of Switching Frequency in the left figure.)

- A blue under-line and variable range of the parameter are appeared.
- Then, you can change the parameters by entering the value directly " (e.g. "60kHz" was changed to "20kHz").

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